








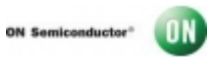


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|  | <h2 style="color: red;">TJ60S06M3L(T6L1,NQ)</h2> | |
| | Hersteller-Teilenummer: | TJ60S06M3L(T6L1,NQ) |
|  | Hersteller / Marke: | Toshiba Semiconductor and Storage |
| | Teil der Beschreibung: | MOSFET P-CH 60V 60A DPAK-3 |
| | Datenblätter: | 1.TJ60S06M3L(T6L1,NQ).pdf 2.TJ60S06M3L(T6L1,NQ).pdf |
| | RoHS Status: | Bleifrei / RoHS-konform |
| Lagerzustand: | New original, Stock Available. | |
| Liefern von: | Hong Kong | |
| Versandweg: | DHL/Fedex/TNT/UPS/EMS | |
| Image may be representation. See specs for product details. | | |

Spezifikationen

| | |
|--|---|
| Teilenummer | TJ60S06M3L(T6L1,NQ) |
| Hersteller | Toshiba Semiconductor and Storage |
| Beschreibung | MOSFET P-CH 60V 60A DPAK-3 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | Require For Quote & Check Stock |
| VGS (th) (Max) @ Id | 3V @ 1mA |
| Technologie | MOSFET (Metal Oxide) |
| Supplier Device-Gehäuse | DPAK+ |
| Serie | U-MOSVI |
| Rds On (Max) @ Id, Vgs | 11.2 mOhm @ 30A, 10V |
| Verlustleistung (max) | 100W (Tc) |
| Verpackung | Tape & Reel (TR) |
| Verpackung / Gehäuse | TO-252-3, DPak (2 Leads + Tab), SC-63 |
| Betriebstemperatur | 175°C (TJ) |
| Befestigungsart | Surface Mount |
| Eingabekapazität (Ciss) (Max) @ Vds | 7760pF @ 10V |
| Gate Charge (Qg) (Max) @ Vgs | 156nC @ 10V |
| Typ FET | P-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 60V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 60A (Ta) |

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RFQ TJ60S06M3L(T6L1,NQ) E-Mail: Info@Y-IC.com

Sie können auch interessiert

| | | | |
|---|---|---|---|
| <p>sein:</p>  <p>TJ60S06M3L TOSHIBA TJ60S06M3L TOSHIBA</p> |  <p>TJ60S04M3L TOSHIBA TJ60S04M3L TOSHIBA</p> |  <p>STB5N62K3 STMicroelectronics MOSFET N-CH 620V 4.2A D2PAK</p> |  <p>IRFD210 Vishay Siliconix MOSFET N-CH 200V 600MA 4-DIP</p> |
|  <p>SI1405DL-T1-E3 Vishay Siliconix MOSFET P-CH 8V 1.6A SC-70-6</p> |  <p>NTMFS4C022NT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 30A 136A 5DFN</p> |  <p>TJ60S04M3L(T6L1,NQ) Toshiba Semiconductor and Storage MOSFET P-CH 40V 60A DPAK-3</p> |  <p>FDP075N15A AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 130A TO- 220-3</p> |

Verwandtes Hot-Keyword

Mehr

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|---|---|--|---|---|
| TJ60S06M3L(T6L1,NQ) Toshiba Semiconductor and Storage | TJ60S06M3L(T6L1,NQ) Datenblatt | TJ60S06M3L(T6L1,NQ)-Datenblätter | TJ60S06M3L(T6L1,NQ) PDF | Toshiba Semiconductor and Storage TJ60S06M3L(T6L1,NQ) |
| TJ60S06M3L(T6L1,NQ) Electronic | TJ60S06M3L(T6L1,NQ)-Komponenten | TJ60S06M3L(T6L1,NQ)-Verteiler | TJ60S06M3L(T6L1,NQ)-Bild | TJ60S06M3L(T6L1,NQ)-Teil |
| TJ60S06M3L(T6L1,NQ) Preis | TJ60S06M3L(T6L1,NQ) Hersteller | TJ60S06M3L(T6L1,NQ) Bild | TJ60S06M3L(T6L1,NQ) Aktie | TJ60S06M3L(T6L1,NQ) Inventar |
| TJ60S06M3L(T6L1,NQ) Neu | TJ60S06M3L(T6L1,NQ) Original | TJ60S06M3L(T6L1,NQ) garantiert | TJ60S06M3L(T6L1,NQ) RFQ | TJ60S06M3L(T6L1,NQ) Online bestellen |

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